



#### P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
001/	150mΩ @ V <sub>GS</sub> = -4.5V	-1.9A
-20V	200mΩ @ V <sub>GS</sub> = -2.5V	-1.7A

#### Description

This MOSFET is designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

# Applications

- Backlighting
- Power Management Functions
- DC-DC Converters
- Motor Control

#### Features

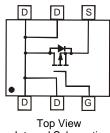
- Very Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT-563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.006 grams (Approximate)



Top View



Internal Schematic

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2104V-7	SOT-563	3000/Tape & Reel

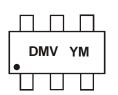
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# **Marking Information**



DMV = Marking Code YM = Date Code Marking Y = Year (ex: T = 2006) M = Month (ex: 0 = Softember

M = Month (ex: 9 = September)

2017

2018

2019

2016

Date Code Ke	у		
Year	2006	2007	 2014
Code	Т	U	 В

Code	Т	U		В	C	;	D	Е		F	G	Н	I
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jı	ul 🛛	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	7	8	9	0	N	D
DMP2104V	P2104V 1 of 6 September 20							ember 2014					

DMP2104V Document number: DS30942 Rev. 8 - 2 2015

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2021

2020



## Maximum Ratings (@T<sub>A</sub> = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V <sub>DSS</sub>	-20	V		
Gate-Source Voltage	V <sub>GSS</sub>	±12	V		
Continuous Drain Current (Note 5) $V_{GS} = -4.5V$	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	-1.9 -1.5	А
Continuous Drain Current (Note 5) $V_{GS}$ = -4.5V	t ≤ 5s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	-2.1 -1.65	А
Continuous Drain Current (Note 5) $V_{GS}$ = -2.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	-1.7 -1.3	A
Pulsed Drain Current	t <sub>p</sub> :	= 10µs	I <sub>DM</sub>	-4.0	А

# **Thermal Characteristics**

Characteristic	Symbol	Value	Units
Power Dissipation (Note 5)	PD	0.85	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R <sub>0JA</sub>	146	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified.)

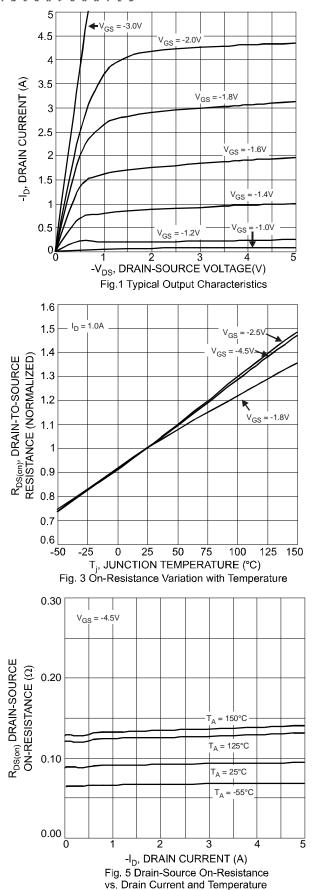
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)								
Drain-Source Breakdown Voltage		<b>BV</b> <sub>DSS</sub>	-20	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	T」= +25°C T」= +125°C	I <sub>DSS</sub>		_	-1.0 -5.0	μA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage		IGSS			±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)							•	
Gate Threshold Voltage		V <sub>GS(th)</sub>	-0.45		-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		R <sub>DS (ON)</sub>	_	92 134 180	150 200 240	mΩ	$\label{eq:VGS} \begin{array}{l} V_{GS} = -4.5V, \ I_D = -950mA \\ \hline V_{GS} = -2.5V, \ I_D = -670mA \\ \hline V_{GS} = -1.8V, \ I_D = -200mA \end{array}$	
Forward Transconductance		<b>g</b> fs		3.1		S	$V_{DS} = -10V, I_{D} = -810mA$	
Diode Forward Voltage (Note 6)		V <sub>SD</sub>	_		-0.9	V	$V_{GS} = 0V, I_{S} = -360mA$	
DYNAMIC CHARACTERISTICS							·	
Input Capacitance		Ciss		320		pF		
Output Capacitance		Coss		80		pF	V <sub>DS</sub> = -16V, V <sub>GS</sub> = 0V f = 1.0MHz	
Reverse Transfer Capacitance		C <sub>rss</sub>		60		pF		

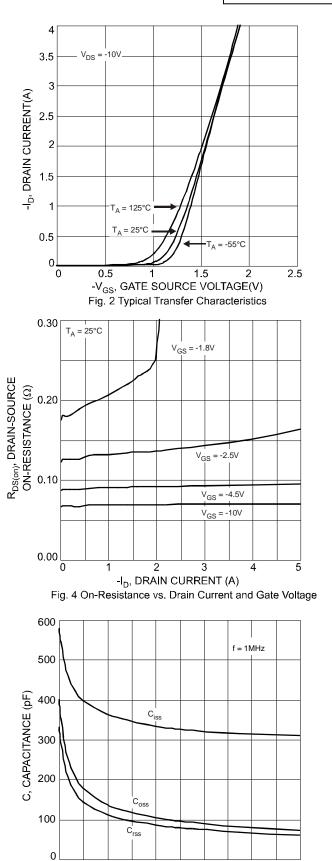
Notes:

Device mounted on FR-4 PCB with 1 inch square pads.
Short duration pulse test used to minimize self-heating effect.

# DMP2104V







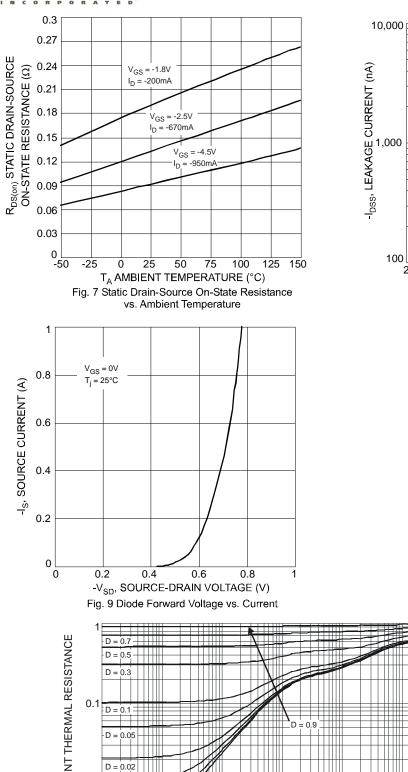
 $0 \quad 2 \quad 4 \quad 6 \quad 8 \quad 10 \quad 12 \quad 14 \quad 16$ 

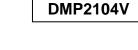
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-V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V)

Fig. 6 Typical Capacitance







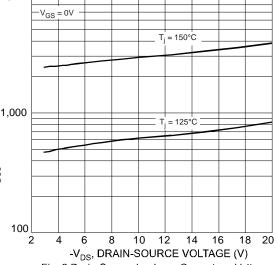
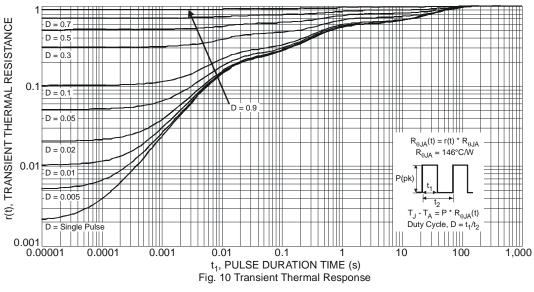


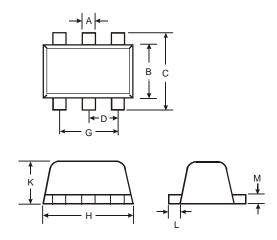
Fig. 8 Drain-Source Leakage Current vs. Voltage





## **Package Outline Dimensions**

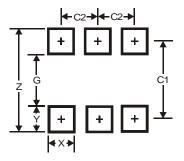
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT-563								
Dim	Min	Max	Тур						
Α	0.15	0.30	0.20						
В	1.10	1.25	1.20						
С	1.55	1.70	1.60						
D	-	-	0.50						
G	0.90	1.10	1.00						
Н	1.50	1.70	1.60						
Κ	0.55	0.60	0.60						
L	0.10	0.30	0.20						
М	0.10	0.18	0.11						
All	Dimens	sions in	mm						

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Y	0.5
C1	1.7
C2	0.5



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